TEXTURE ANALYSIS IN LD-MOCVD PROCESSED THIN FILM GIANT MAGNETORESISTANT (LaM)MnO$_3$ MATERIALS

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Thin films of La$_{0.67}$Mn$_{0.33}$O$_3$ (M = Sr), LSMO were deposited on three different substrates of LAO, Sapphire, and Y-ZrO$_2$ (YSZ) using metal–organic chemical vapor deposition methods. The effect of texture and orientation on the resistance ($0$ and $6$ T) and magnetoresistance (MR) of (LSMO) thin films on various substrates has been investigated. X-ray pole figures were measured using Philips X’Pert X-ray diffractometer equipped with the PopLa analysis package. A direct correlation was observed between the lattice mismatch strain and the structure of the thin film growth. LSMO/LAO seems to be the most perfect system for epitaxial growth due to the negligible lattice-mismatch (~2%). The dominant orientation changes for the films deposited on LAO [100] and LAO [110] substrates while the transition temperature from ferromagnetic to paramagnetic state of the film on LAO [110] is 50 K higher than that of the film on LAO [100]. The MR data and TMI temperature were measured using standard 4-point resistivity devices and SQUID.

Keywords: Epitaxy; Texture measurement; (LaM)MnO$_3$ GMR films

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INTRODUCTION

Much research has been invested in producing thin film epitaxial GMR (LaM)MnO₃ materials and optimizing their magnetic properties that are critical in applications such as magnetic sensor and recording devices (Petrov et al., 1998; Jin et al., 1994; Hawley et al., 1995). Recent studies on the production of thin film using metal–organic chemical vapor deposition methods (MOCVD) (Dahmen et al., 1997a,b; Gillman et al., 1997) have revealed that the microstructure and the consequent property of the film material depends on the substrate and the deposition parameters. More recently it was shown that the preferred orientation (texture) of the thin film also depends on the type of the substrate and its orientation (Li et al., 1998). Lattice mismatch is one of the most important parameters in this process. In an earlier study (recent work, Weaver et al.), we have described texture development and critical thickness of LCMO films on LAO, MgO and YSZ substrates. In this paper more careful investigation of texture development for polycrystalline thin films have been performed for a carefully selected number of substrates of varying lattice mismatch. In this investigation the thin film material chosen is La₀.₆₇Sr₀.₃₃MnO₃ with a lattice constant of 3.882 Å. The structure of this composite is believed to have monoclinic symmetry at low temperatures and the β angle becomes closer to 90° as the fraction of Sr increases (Hashimoto, 1987).

EXPERIMENTAL PROCEDURE

Thin films of lanthanum manganites were deposited by metal–organic chemical vapor deposition (MOCVD) on three different types of substrates of [100] oriented yttrium stabilized zirconia (YSZ), and LaAlO₃ (LAO) with two orientations of [100] and [110] and Sapphire oriented at [0001] (Table 1). A liquid delivery vaporization system (NZ-Applied Technologies) was used to deliver the 2,2,6,6-tetramethyl-3,5-heptanedionato (TMHD) organometallic precursors, La(TMHD)₃, Mn(TMHD)₃, and Sr(TMHD)₂, which were diluted in 25 ml of freshly distilled solvent (diglyme) and vaporized (T=250°C) at rates of 0.33 and 1.66 μl/min. The gaseous mixture was then introduced to an EMCORE reactor. The substrates were held at a temperature of 700°C
TABLE I  d-Spacing and lattice mismatch for the film of (La_{0.67}Mn_{0.33})MnO_{3} films deposited on various substrates \( MR = \left[ R(0) - R(5T) \right]/R(0) \)

<table>
<thead>
<tr>
<th>Film/substrate</th>
<th>d-Spacing (Å)</th>
<th>Lattice mismatch (%)</th>
<th>Resistance (Ω)</th>
<th>( T(MI) ) (K)</th>
<th>MR% (max)</th>
</tr>
</thead>
<tbody>
<tr>
<td>( \text{La}<em>{0.67}\text{Sr}</em>{0.33}\text{MnO}<em>{3}/\text{LaAlO}</em>{3} ) [100]</td>
<td>3.8833 (100)</td>
<td>2.321</td>
<td>330</td>
<td>362</td>
<td>37</td>
</tr>
<tr>
<td>( \text{La}<em>{0.67}\text{Sr}</em>{0.33}\text{MnO}<em>{3}/\text{LaAlO}</em>{3} ) [110]</td>
<td>2.7412 (110)</td>
<td>2.308</td>
<td>880</td>
<td>339</td>
<td>27</td>
</tr>
<tr>
<td>( \text{La}<em>{0.67}\text{Sr}</em>{0.33}\text{MnO}_{3}/\text{sapphire} ) [0001]</td>
<td>2.7343 (110)</td>
<td>26.739</td>
<td>14000</td>
<td>200</td>
<td>—</td>
</tr>
<tr>
<td>( \text{La}<em>{0.67}\text{Sr}</em>{0.33}\text{MnO}_{3}/\text{YSZ} ) [100]</td>
<td>2.7320 (110)</td>
<td>6.725</td>
<td>13000</td>
<td>221</td>
<td>30</td>
</tr>
</tbody>
</table>

during the experiment. Nitrogen (100 sccm) was used as a carrier gas and oxygen (300 sccm) and N_{2}O (500 sccm) served as oxidants. The deposition rate was approximately 15 Å/min. The reactor pressure was 5 Torr. After deposition the films were slowly cooled under reaction conditions until the susceptor temperature was below 100°C when the substrates were removed from the susceptor.

To investigate texture low angle XRD scans \( (Q = 2^\circ) \), normal \( 2\theta/\Omega \) scans and pole figure analysis were conducted on Siemens D-500 and Philips X'Pert MRD diffractometers operated at 40 kV and 50 mA using CuK\( \alpha \) radiation. The pole figure diffractometer was additionally equipped with a graphite monochromator. Incomplete pole figures were obtained using the reflection technique described by Schultz (1949). The resulting data was analyzed via the spherical harmonics method using the PopLA software package (Kallend et al., 1991) from which the complete and inverse pole figures were reconstructed using the spherical harmonics approach.

**Experimental Results**

The XRD direct pole figures for the thin film material grown on LAO oriented at [110] (Fig. 1) show an oriented growth as evidenced by the presence of only the [011] type reflections in the X-ray scan. This suggests that the film grows as a single crystal. Interestingly enough thin film materials grown on substrates oriented at [100] direction exhibit a dominant orientation of [100] (Fig. 2). This can be explained based on the low lattice mismatch between the thin film and the LAO substrate (LSMO: \( a = 3.882 \) Å; LAO: \( a = 3.792 \) Å). This results into a lattice...
mismatch of 2.321% for the LAO [001] and 2.308% for LAO oriented at [011].

The direct pole figures for the thin film materials grown on YSZ oriented at [110] shows evidence for a polycrystalline thin film (Fig. 3). The [100] pole figure shows that the thin film material is axisymmetric with respect to [100] orientation. This suggests that the thin film has grown epitaxially around the dominant orientation. This is verified by an Orientation Distribution Function (ODF) analysis of the pole figure data. The ODF analysis was performed using the three pole figures of [110], [111], and [200]. Inverse pole figures were produced using the ODF data. The inverse pole figure for the normal plane shows that there exists a dominant texture component at [233] orientation (Fig. 4).
FIGURE 2  \( \text{La}_{0.8}\text{Sr}_{0.2}\text{MnO}_3 \) grown on LAO [100]. (a) [100] pole figure; (b) [110] pole figure.

FIGURE 3  Direct (001) pole figure for the LSMO film grown on YSZ oriented at [110].
FIGURE 4 Recalculated normal plane inverse pole figure for the LSMO/YSZ.

FIGURE 5 Recalculated direct [233] pole figure for the LSMO film grown on YSZ.

The ODF analysis shows a texture intensity of 2.3 times random for this orientation. The recalculated direct pole figure for [233] shows that the polycrystalline thin film grows primarily at this orientation (Fig. 5). The other two in-plane inverse pole figures exhibit a near random texture (a maximum intensity of 1.5 times random). This is more evidence for epitaxial growth.

The direct pole figures for LSMO on Sapphire [0001] shows similar behavior as YSZ (Fig. 6). The ODF analysis was performed using the three pole figures of [100], [110], and [111]. The inverse pole figure for the normal plane direction shows that there are two texture components for the polycrystalline thin film (Fig. 7). One of them shows up at
FIGURE 6  Direct (001) pole figure for the LSMO film grown on sapphire oriented at [0001].

FIGURE 7  Inverse pole figure for the normal plane LSMO/sapphire.

the same orientation as the YSZ substrate, [233] orientation with a texture intensity of 2.7 times random. A direct pole figure in the [233] orientation shows that this is the dominant orientation in the growth of the thin (Fig. 8). The maximum intensity for the two other in-plane inverse pole figures is 1.2, which is evidence for the epitaxial growth. A second weaker texture component also showed up at [114] orientation with a texture intensity of 1.7 times random.

The results of the texture studies can be explained based on the lattice mismatch of the polycrystalline films. The lattice mismatch for the YSZ substrate is 6.7% whereas the one for the Sapphire is 26.7%. The thin
film material grown on Sapphire less texture (2.3 compared to 2.7) because of the higher lattice mismatch. A second texture component, $[114]$, also becomes apparent in this film. The thin film deposited on LAO substrate with the lowest lattice mismatch was monocrystalline (or infinitely textured).

The results of this work are correlated to the magnetic property measurements. Epitaxial LSMO [100] and LSMO [110] films on LaAlO$_3$ (LAO) [100] and [110] substrates show MR ratios which are sharply peaked at the $T$(MI) (metal--insulator transition). The $T$(MI) of LCMO [110] is 20 K lower than for LCMO [100] film. The MR value is also slightly smaller for the films on LAO [110] (Table I). Polycrystalline films on Y-ZrO$_2$ (YSZ) and Sapphire show a nearly constant MR ratio below $T$(MI).

Due to the polycrystalline nature of the films on SAP [0001] and YSZ [001] a greater resistance is found than with the monocrystalline films on LAO, particularly for $T \ll T$(MI). The results correlate well with the lattice match of the substrate and the LSMO films: the larger the lattice mismatch the higher the resistance of the film and the lower the $T$(MI). Similar low temperature MR has recently been observed in both Sr and Ca doped manganites. The proposed explanation for the low temperature MR in polycrystalline films is spin-polarized tunneling at the grain boundaries (Hwang et al., 1996; von Helmolt et al., 1995).

The magnetic anisotropy in thin epitaxially films on LAO [100] and LAO [110] can be interpreted in terms of substrate induced stress. The physics in these CMR materials is governed by an interplay of the Mn $e_g$
electrons with its double exchange connection to magnetization and the localized effect of strong electron–lattice coupling (Millis et al., 1998; Thomas et al., 1998; Millis, 1998; Suzuki et al., 1997; Jin, 1997; Garcia Munoz et al., 1997). Therefore a uniform compression should increase the electron hopping and reduce the electron–lattice coupling while a uniform biaxial distortion should increase the Jahn–Teller (Goodenough et al., 1961) splitting such that increasingly electrons become more localized. Further investigations are on their way to determine the role of the strain in these CMR materials.

CONCLUSION

The results show that Sapphire substrate with the largest lattice mismatch produce the most polycrystalline thin film material with the lowest texture. Thin films grown on LAO substrate with a lattice mismatch of less than 2.4% resulted in a monocrystalline microstructure. Such results are explained based on the fact that the high lattice mismatch substrates produce a planar defect at the interface and the strain energy due to large lattice mismatch creates a planar defect (microplasticity, dislocation structure, …) which can alleviate local stresses. Differences in the MR can be attributed to grain boundary effects and to strain.

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References


